## NSN 5962-01-365-1427

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Body Length:
1.710 inches
Body Height:
0.290 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Lug in unit e/i fscm 76301
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-14 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, memory, 2kx8 cmos, static ram (dual port) monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts applied and 7.0 volts applied
Time Rating Per Chacteristic:
90.00 nanoseconds af output megawatts
Memory Device Type:
Ram
Hybrid Technology Type:
Monolithic
Test Data Document:
$67268-5962-87002\ standard\ (includes\ industry\ or\ association\ standards,\ individual\ manufactureer\ standards,\ etc.).$
Terminal Type And Quantity:
48 printed circuit
Specification Data:
96906-mil-std-883 government standard
Shelf Life:

N/a

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Demilitarization:

No

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